

30V NPN SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

Features

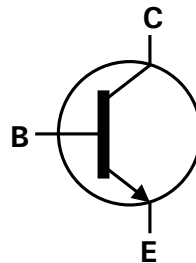
- $BV_{CEO} > 30V$
- Max Continuous Current $I_C = 1A$
- Low Saturation Voltage
- Complementary PNP Type: FZT589
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

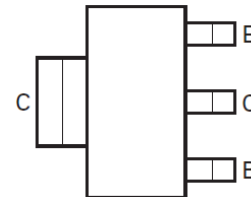
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (approximate)



Top View



Device Symbol



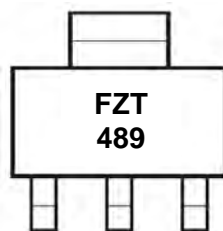
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT489TA	AEC-Q101	FZT489	7	12	1,000
FZT489QTA	Automotive	FZT489	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



FZT489 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	1	A
Base Current	I _B	200	mA
Peak Pulse Current	I _{CM}	4	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

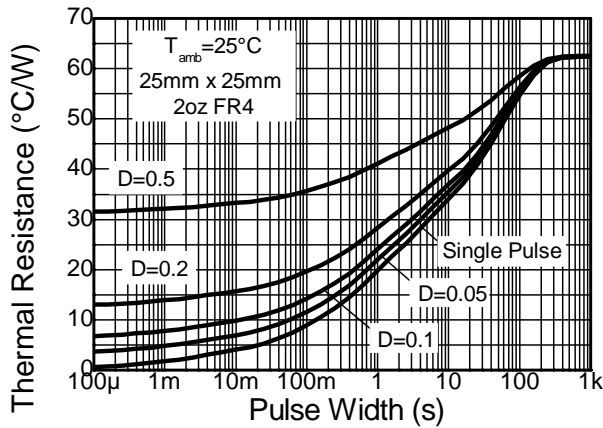
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 6) 2	W
		(Note 7) 3	W
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 6) 62.5	°C/W
		(Note 7) 41.7	°C/W
Thermal Resistance, Junction to Leads (Note 8)	R _{θJL}	19.41	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

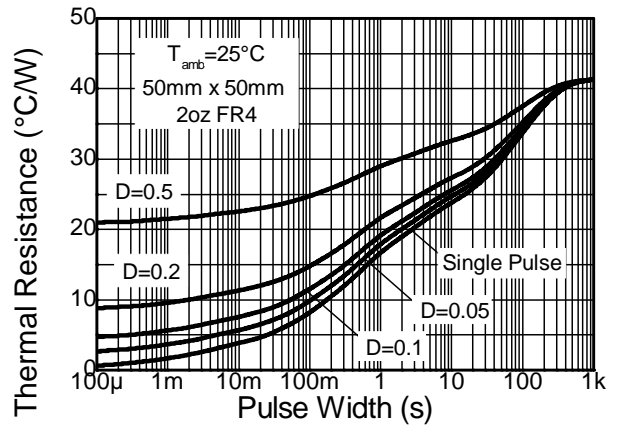
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
6. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
 7. Same as note (6), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

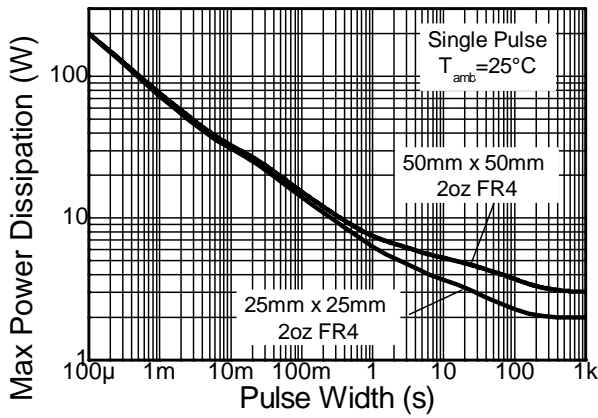
Thermal Characteristics and Derating Characteristics



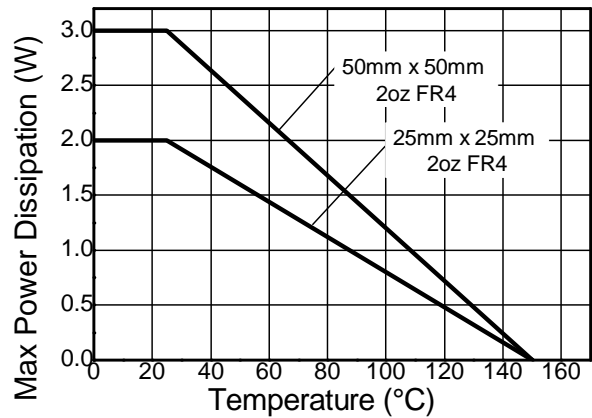
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



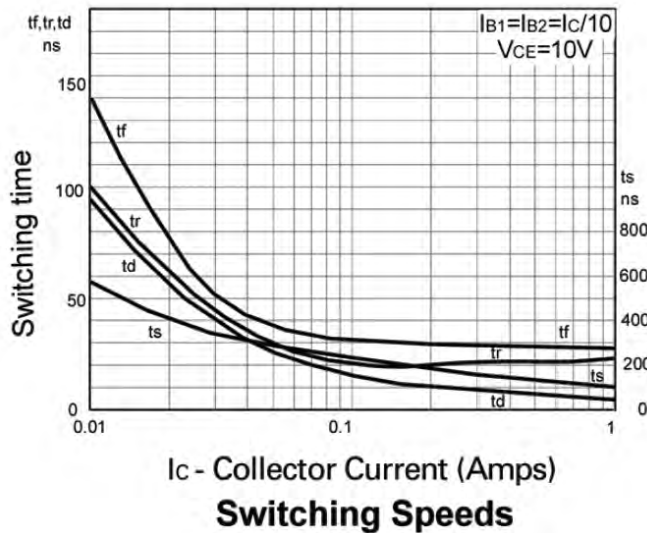
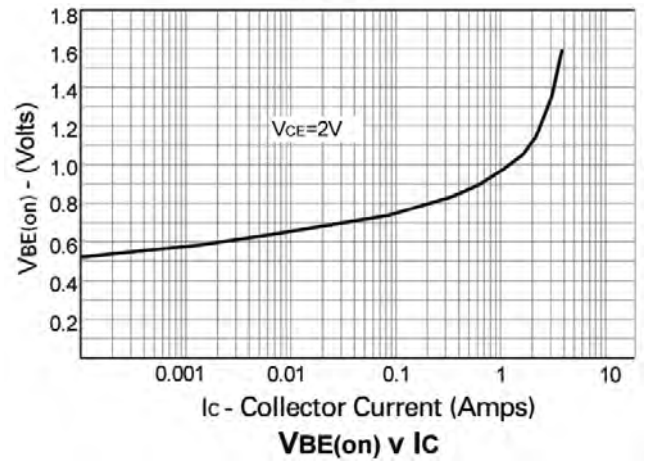
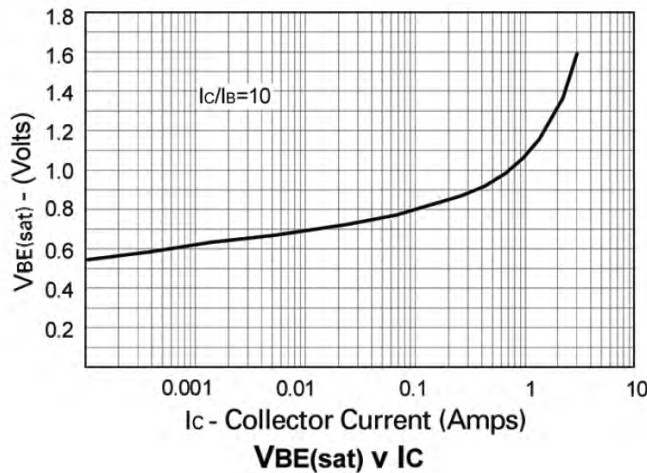
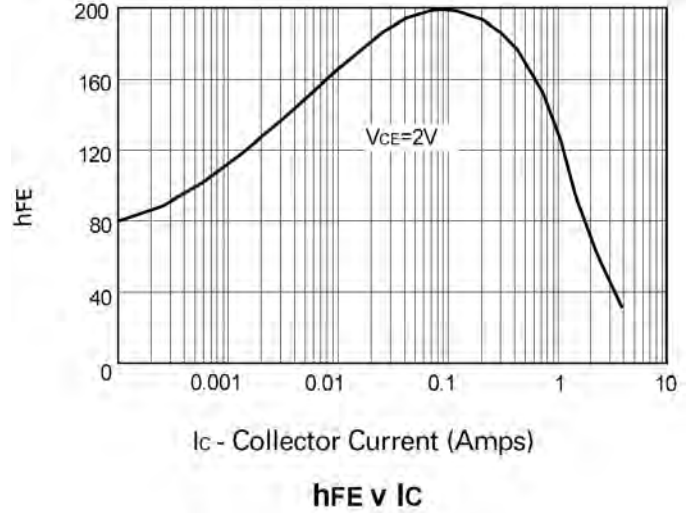
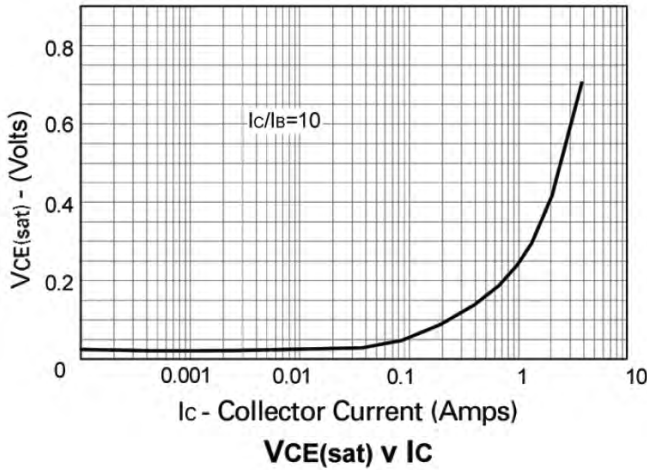
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	–	–	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	30	–	–	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	–	–	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	–	–	100	nA	V _{CB} = 30V
Collector Cut-off Current	I _{CES}	–	–	100	nA	V _{CE} = 30V
Emitter Cut-off Current	I _{EBO}	–	–	100	nA	V _{EB} = 4V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	–	–	0.3 0.6	V	I _C = 1A, I _B = 100mA I _C = 2A, I _B = 200mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	–	–	1.1	V	I _C = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	–	–	1.0	V	I _C = 1A, V _{CE} = 2V
DC Current Gain (Note 10)	h _{FE}	100 100 60 20	– – – –	– 300 – –	–	I _C = 1mA, V _{CE} = 2V I _C = 1A, V _{CE} = 2V I _C = 2A, V _{CE} = 2V I _C = 4A, V _{CE} = 2V
Current Gain-Bandwidth Product (Note 10)	f _T	150	–	–	MHz	V _{CE} = 10V, I _C = 50mA f = 100MHz
Output Capacitance (Note 10)	C _{obo}	–	–	10	pF	V _{CB} = 10V, f = 1MHz

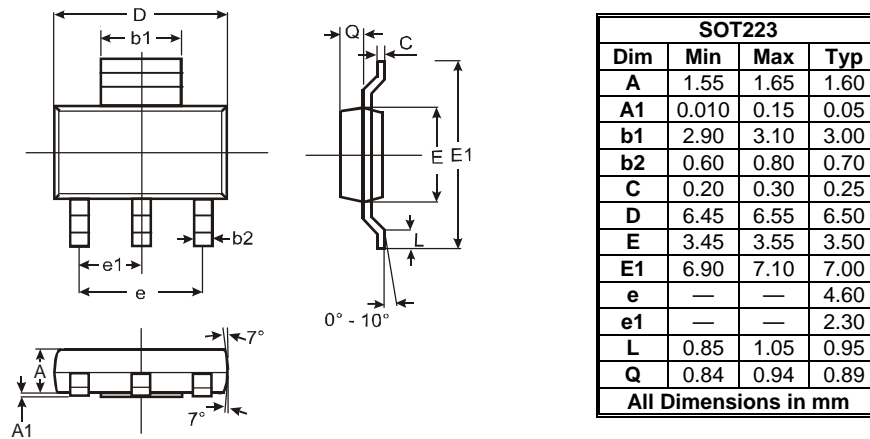
Notes: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



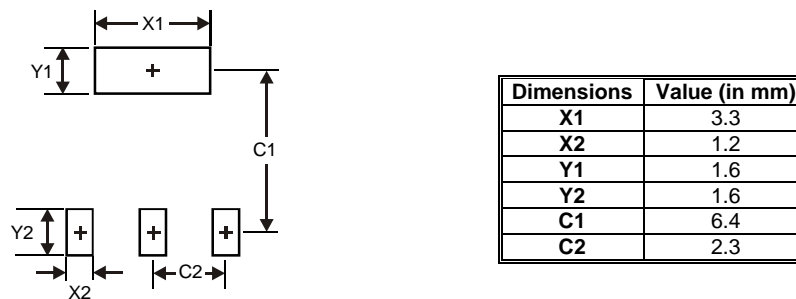
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



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